

2SK1460

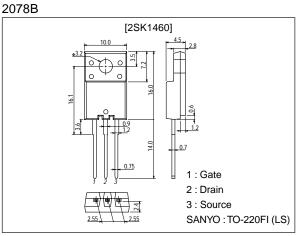
# **Ultrahigh-Speed Switching Applications**

### Features

- · Low ON-state resistance.
- $\cdot$  Ultrahigh-speed switching.
- · Micaless package facilitating mounting.

### Package Dimensions

unit:mm



## **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

| Parameter                   | Symbol           | Conditions             | Ratings     | Unit |
|-----------------------------|------------------|------------------------|-------------|------|
| Drain-to-Source Voltage     | V <sub>DSS</sub> |                        | 900         | V    |
| Gate-to-Source Voltage      | V <sub>GSS</sub> |                        | ±30         | V    |
| Drain Current (DC)          | ۱ <sub>D</sub>   |                        | 3.5         | А    |
| Drain Current (Pulse)       | I <sub>DP</sub>  | PW≤10µs, duty cycle≤1% | 7           | А    |
| Allowable Power Dissipation | D-               |                        | 2.0         | W    |
|                             | PD               | Tc=25°C                | 40          | W    |
| Channel Temperature         | Tch              |                        | 150         | °C   |
| Storage Temperature         | Tstg             |                        | -55 to +150 | °C   |

#### Electrical Characteristics at Ta = 25°C

| Parameter                                  | Symbol              | Conditions                                | Ratings |     |      | Unit |
|--|---------------------|---|---------|-----|------|------|
|  |                     |   | min     | typ | max  |      |
| Drain-to-Source Breakdown Voltage          | V(BR)DSS            | I <sub>D</sub> =1mA, V <sub>GS</sub> =0   | 900     |     |      | V    |
| Zero-Gate Voltage Drain Current            | IDSS                | V <sub>DS</sub> =900V, V <sub>GS</sub> =0 |         |     | 1.0  | mA   |
| Gate-to-Source Leakage Current             | IGSS                | V <sub>GS</sub> =±30V, V <sub>DS</sub> =0 |         |     | ±100 | nA   |
| Cutoff Voltage                             | VGS(off)            | V <sub>DS</sub> =10V, I <sub>D</sub> =1mA | 2.0     |     | 3.0  | V    |
| Forward Transfer Admittance                | yfs                 | V <sub>DS</sub> =20V, I <sub>D</sub> =2A  | 1.0     | 2.0 |      | S    |
| Static Drain-to-Source ON-State Resistance | R <sub>DS(on)</sub> | I <sub>D</sub> =2A, V <sub>GS</sub> =10V  |         | 2.8 | 3.6  | Ω    |
|  | 20(01)              | 2 00                                      |         | · · |      |      |

(Note) Be careful in handling the 2SK1460 because it has no protection diode between gate and source.

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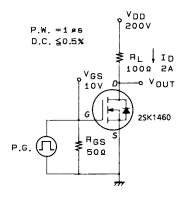
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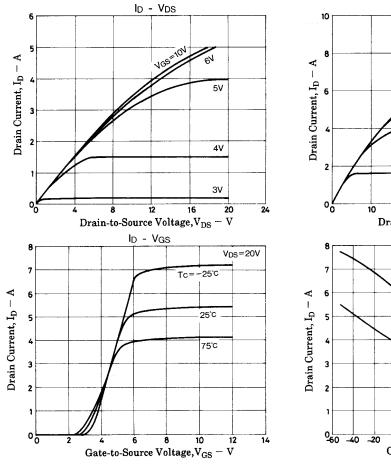
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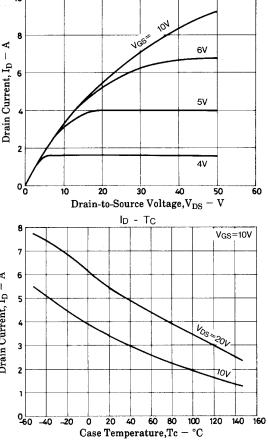
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| Parameter                    | Symbol          | Conditions  | Ratings |     |     | Unit |
|------------------------------|-----------------|---|---------|-----|-----|------|
|                              | Symbol          |   | min     | typ | max | Unit |
| Input Capacitance            | Ciss            | V <sub>DS</sub> =20V, f=1MHz  |         | 700 |     | pF   |
| Output Capacitance           | Coss            | V <sub>DS</sub> =20V, f=1MHz  |         | 300 |     | pF   |
| Reverse Transfer Capacitance | Crss            | V <sub>DS</sub> =20V, f=1MHz  |         | 170 |     | pF   |
| Turn-ON Delay Time           | td(on)          | I <sub>D</sub> =2A, V <sub>GS</sub> =10V, V <sub>DD</sub> =200V, R <sub>GS</sub> =50Ω |         | 15  |     | ns   |
| Rise Time                    | tr              | I <sub>D</sub> =2A, V <sub>GS</sub> =10V, V <sub>DD</sub> =200V, R <sub>GS</sub> =50Ω |         | 35  |     | ns   |
| Turn-OFF Delay Time          | td(off)         | I <sub>D</sub> =2A, V <sub>GS</sub> =10V, V <sub>DD</sub> =200V, R <sub>GS</sub> =50Ω |         | 200 |     | ns   |
| Fall Time                    | tf              | I <sub>D</sub> =2A, V <sub>GS</sub> =10V, V <sub>DD</sub> =200V, R <sub>GS</sub> =50Ω |         | 65  |     | ns   |
| Diode Forward Voltage        | V <sub>SD</sub> | I <sub>S</sub> =3.5A, V <sub>GS</sub> =0  |         |     | 1.8 | V    |

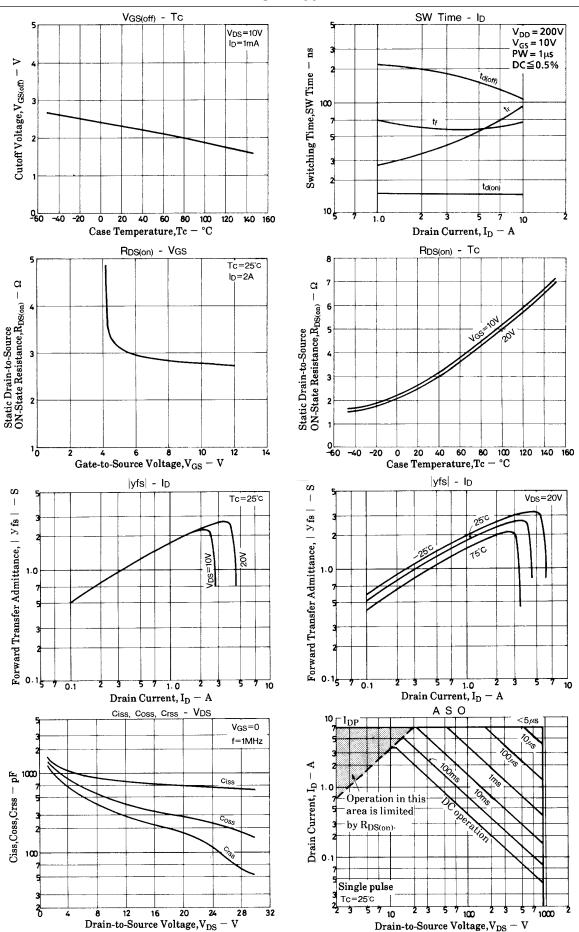
#### Switching Time Test Circuit



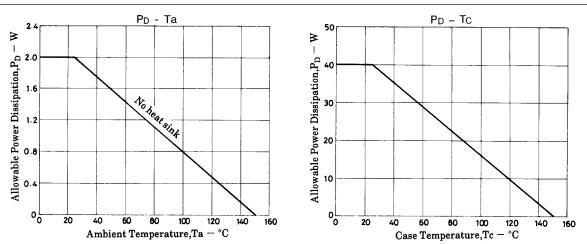




ID - VDS



No.3463-3/4



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